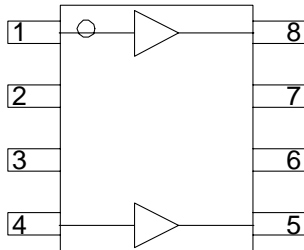




Product Description

Sirenza Microdevice's CGA-3318 is a high performance Silicon Germanium HBT MMIC Amplifier. Designed with SiGe process technology for excellent linearity at an exceptional price. A Darlington configuration is utilized for broadband performance. The heterojunction increases breakdown voltage and minimizes leakage current between junctions. The CGA-3318 contains two amplifiers for use in wideband Push-Pull CATV amplifiers requiring excellent second order performance. The second and third order non-linearities are greatly improved in the push pull configuration.

Amplifier Configuration



ELECTRICAL SPECIFICATIONS

Symbol	Parameter	Freq.(MHz)	Min.	Typ.	Max.	Units
G	Small Signal Gain	5		13.2		dB
		50		12.5		
		500		12.5		
		870	10.0	12.0		
OIP2	Output Second Order Intercept Point Tone Spacing = 1 MHz, Pout per tone = +6 dBm	50		69.0		dBm
		250		71.5		
		500	67.0	69.0		
OIP3	Output Third Order Intercept Point Tone Spacing = 1 MHz, Pout per tone = +6 dBm	50		36.5		dBm
		500		38.0		
		870	36.0	38.0		
P1dB	Output Power at 1dB Gain Compression	50		20.0		dBm
		500		21.0		
		870	18.6	20.6		
IRL	Input Return Loss	500		17.0		dB
		50-870	10			
ORL	Output Return Loss	500		12.0		dB
		50-870	10			
NF	Noise Figure Balun Insertion Loss Included	50		4.2		dB
		500		4.3		
		870		5.0	6.0	
CSO	Worst Case Over Band, 79 Ch., Flat, +34dBmV			70		dBc
CTB	Worst Case Over Band, 79 Ch., Flat, +34dBmV			68		dBc
XMOD	Worst Case Over Band, 79 Ch., Flat, +34dBmV			63		dBc
V_D	Device Operating Voltage		3.9	4.1	4.3	V
I_D	Device Operating Current		135	150	165	mA
$R_{TH(J-L)}$	Thermal Resistance (Junction to Lead)			50		°C/W

The information provided herein is believed to be reliable at press time. Sirenza Microdevices assumes no responsibility for inaccuracies or omissions. Sirenza Microdevices assumes no responsibility for the use of this information, and all such information shall be entirely at the user's own risk. Prices and specifications are subject to change without notice. No patent rights or licenses to any of the circuits described herein are implied or granted to any third party. Sirenza Microdevices does not authorize or warrant any Sirenza Microdevices product for use in life-support devices and/or systems. Copyright 2005 Sirenza Microdevices, Inc.. All worldwide rights reserved.

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CGA-3318

CGA-3318Z



Dual CATV Broadband High Linearity SiGe HBT Amplifier



Product Features

- Available in Lead free, RoHS compliant, & Green packaging
- Excellent CSO/CTB/XMOD Performance at +34 dBmV Output Power per Tone
- Dual Devices in each SOIC-8 Package simplify Push-Pull configuration PC board layout
- 5 to 900 MHz operation

Applications

- CATV Head End Driver and Predriver Amplifier
- CATV Line Driver Amplifier

Absolute Maximum Ratings

Parameter	Absolute Limit
Max Device Current (I_D)	225 mA
Max Device Voltage (V_D)	6 V
Max. RF Input Power	+18 dBm
Max. Junction Temp. (T_J)	+150°C
Operating Temp. Range (T_L)	-40°C to +85°C
Max. Storage Temp.	+150°C

Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one.

Bias Conditions should also satisfy the following expression:

$$I_D V_D < (T_J - T_L) / R_{TH}, \text{ j-l} \quad T_L = T_{LEAD}$$

Reliability & Qualification Information

Parameter	Rating
ESD Rating - Human Body Model (HBM)	Class 1B
Moisture Sensitivity Level	MSL 1

This product qualification report can be downloaded at
www.sirenza.com

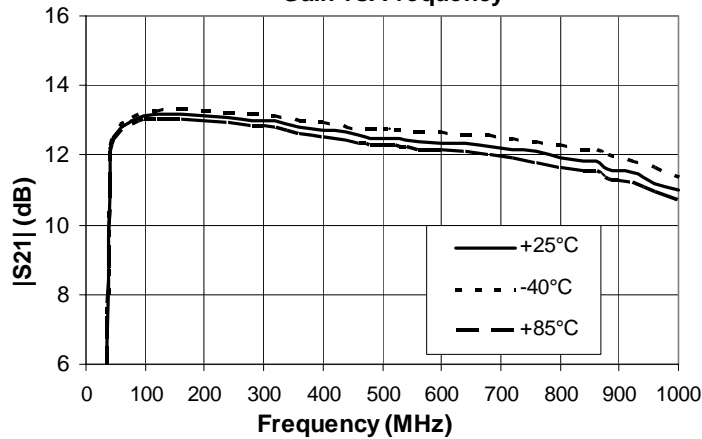


Caution: ESD sensitive

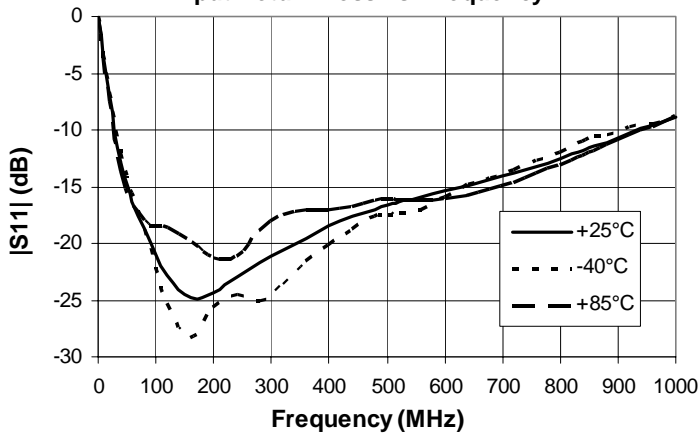
Appropriate precautions in handling, packaging and testing devices must be observed.

Typical RF Performance: $V_S=8V$, $I_D=150mA$ @ $T_L=+25^\circ C$, $R_{BIAS}=51$ Ohms, Push-Pull Configuration

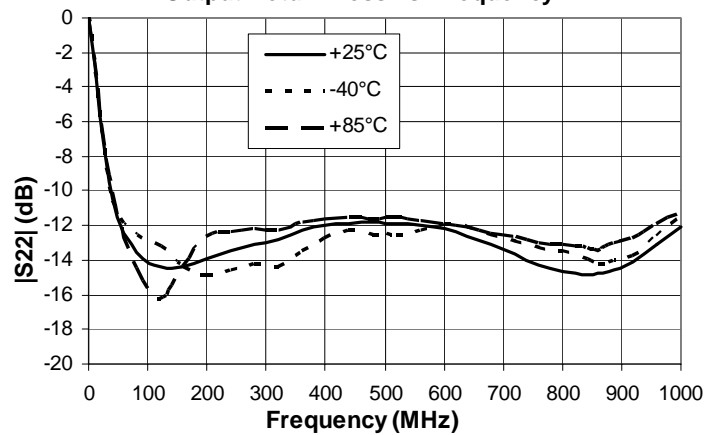
Gain vs. Frequency



Input Return Loss vs. Frequency

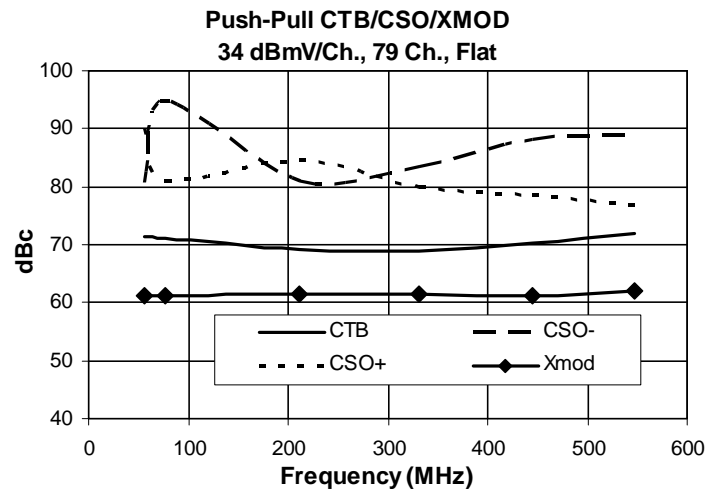
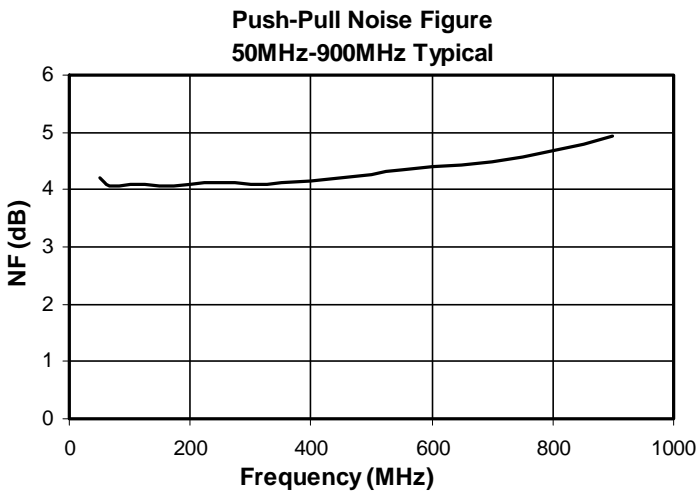
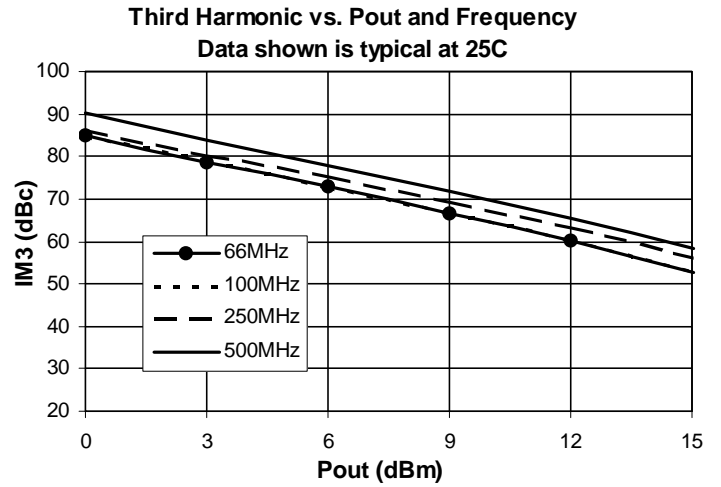
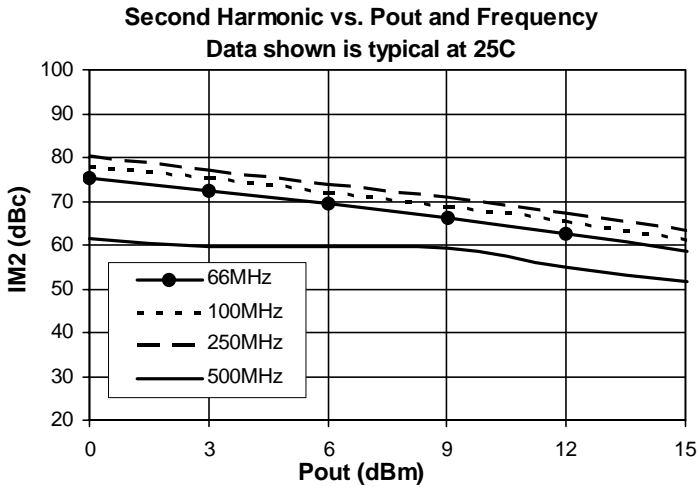
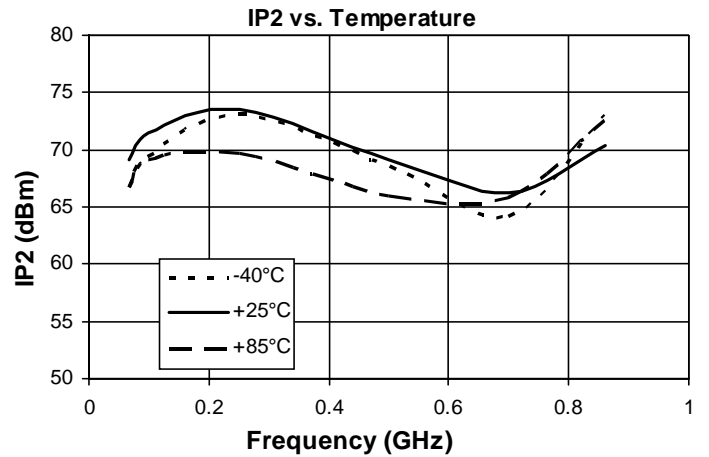
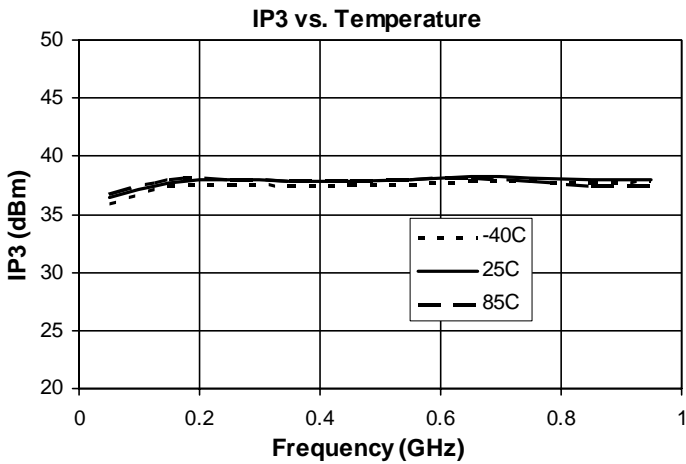


Output Return Loss vs. Frequency



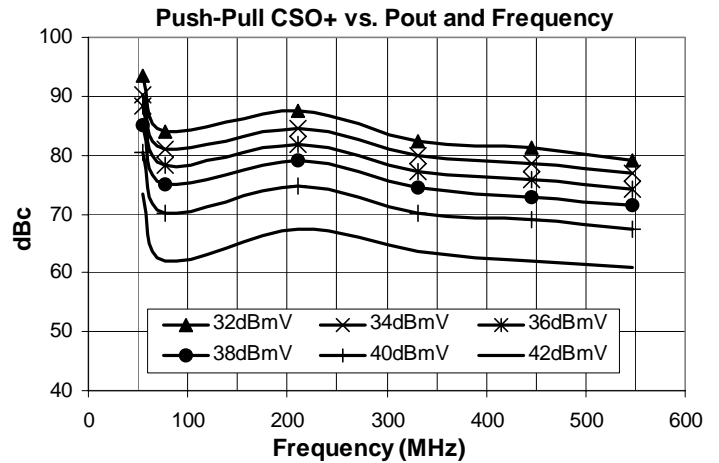
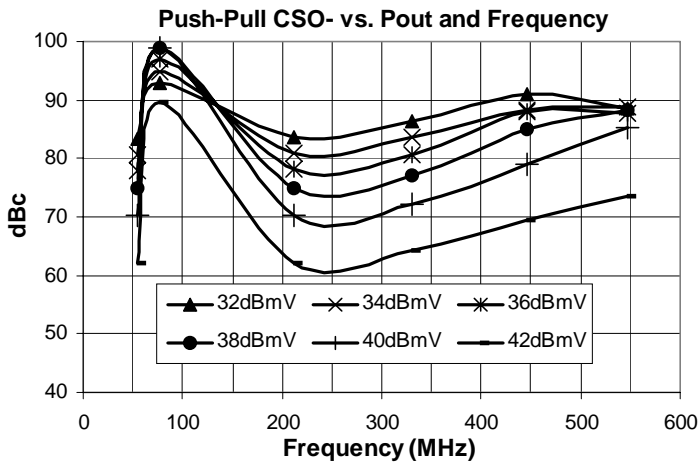
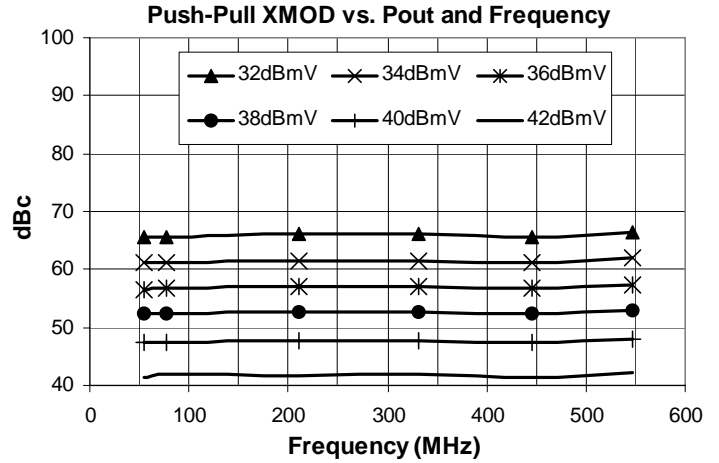
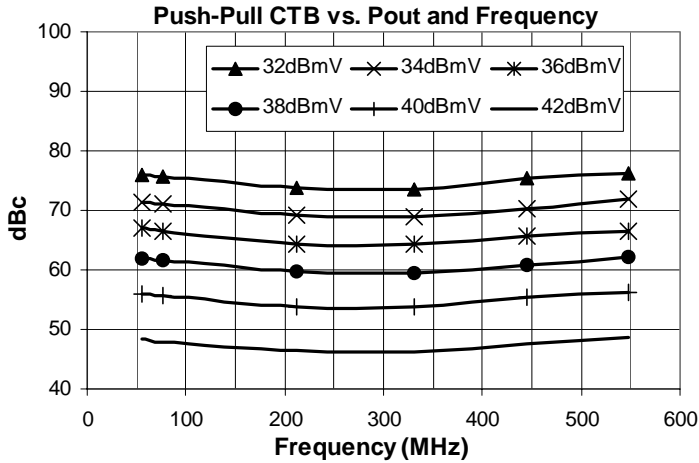
75 Ohm Push Pull S-parameters are available for download at www.sirenza.com

Typical RF Performance: $V_s=8V$, $I_D=150mA$ @ $T_L=+25^\circ C$, $R_{BIAS}=51$ Ohms, Push-Pull Configuration



CSO/CTB/XMOD Performance:

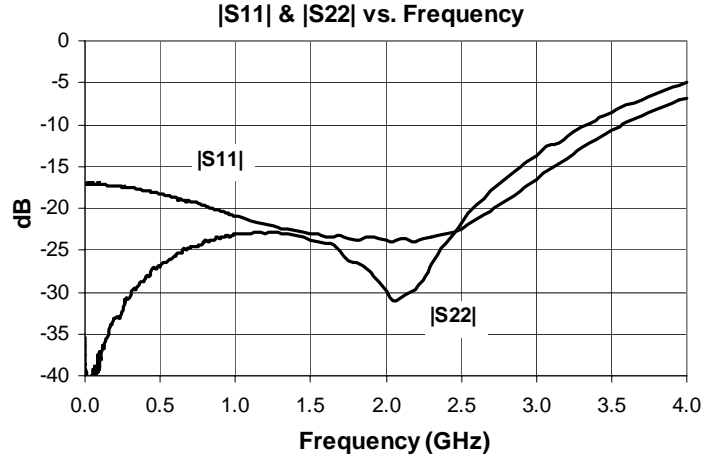
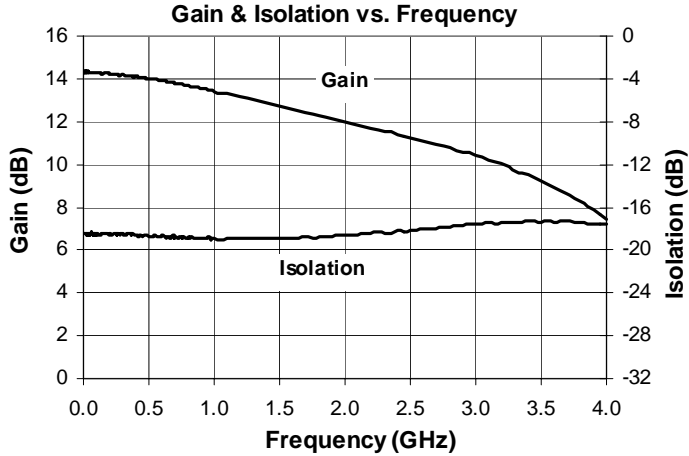
$V_S=8V$, $I_D=150mA$ @ $T_L=+25^\circ C$, $R_{BIAS}=51$ Ohms, Push-Pull Config, 79 Ch. Flat Analog, No Digital Channels.



Note: CSO measurements > 85 dBc can be limited by system noise.

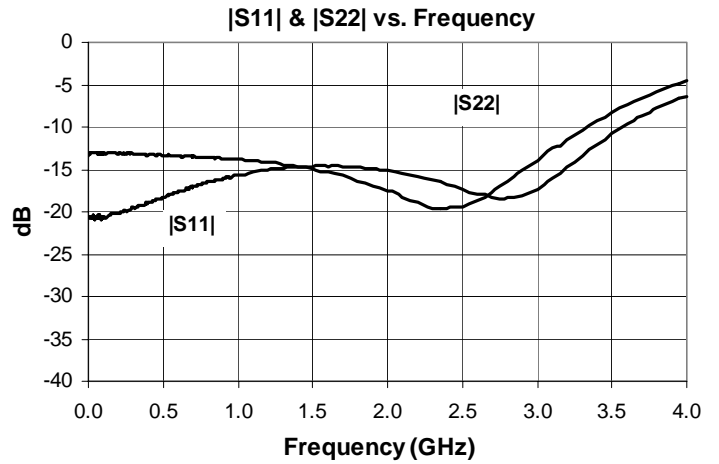
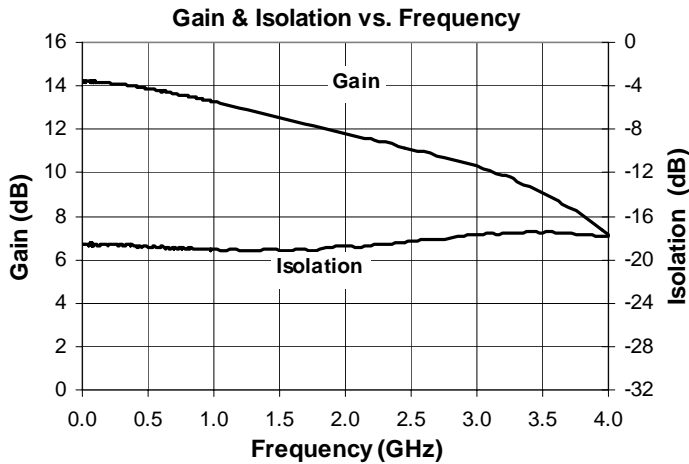
Typical RF Performance - Single Ended - 50 Ohm System

$V_s=8V$, $I_D=75mA$ (one amp biased), $T_L=+25^\circ C$, $R_{BIAS}=51$ Ohms



Typical RF Performance - Single Ended - 37.5 Ohm System

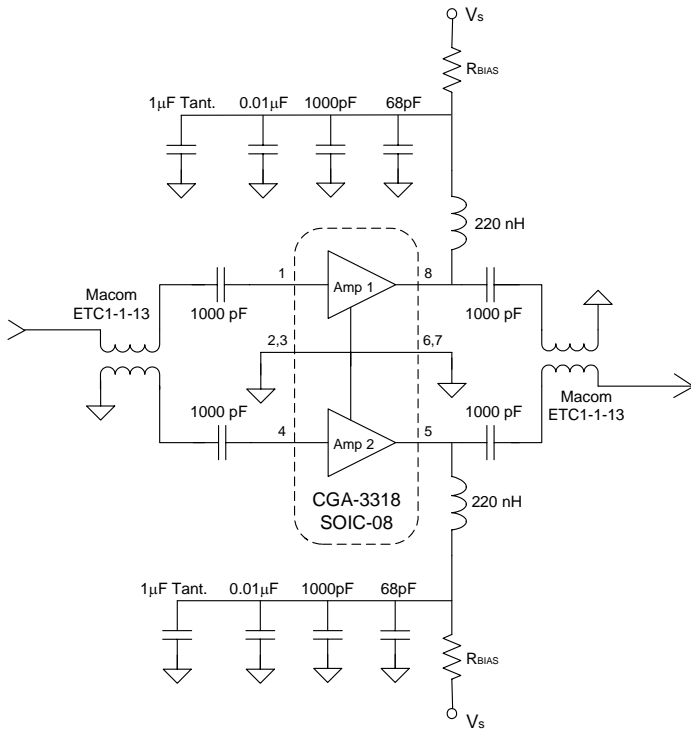
$V_s=8V$, $I_D=75mA$ (one amp biased), $T_L=+25^\circ C$, $R_{BIAS}=51$ Ohms



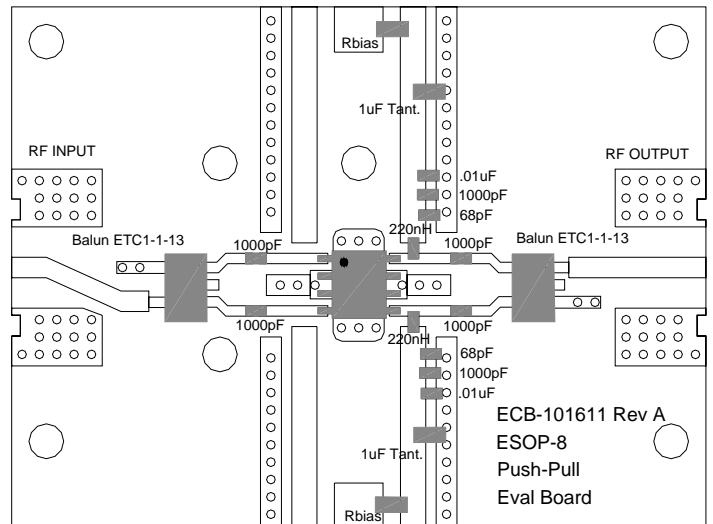
50 Ohm and 37.5 Ohm Single Ended S-parameter files are available for download at www.sirenza.com

Pin #	Function	Description	Device Pin Out
1	RF IN Device 1	RF input pin. This pin requires the use of an external DC blocking capacitor as shown in the schematic.	
2,3	Ground	Connection to ground. Use via holes for best performance to reduce lead inductance as close to ground leads as possible.	
4	RF IN Device 2	Same as pin 1	
5	RF OUT / Vcc Device 2	RF output and bias pin. Bias should be supplied to this pin through an external series resistor and RF choke inductor. Because DC biasing is present on this pin, a DC blocking capacitor should be used in most applications (see application schematic). The supply side of the bias network should be well bypassed.	
6,7	Ground	Same as pins 2 and 3	
8	RF OUT / Vcc Device 1	Same as pin 5	
EPAD	Ground	Exposed area on the bottom side of the package must be soldered to the ground plane of the board for optimum thermal and RF performance. Several vias should be located under the EPAD as shown in the recommended land pattern on page 5.	

50-870 MHz Application Schematic



50-870 MHz Evaluation Board Layout



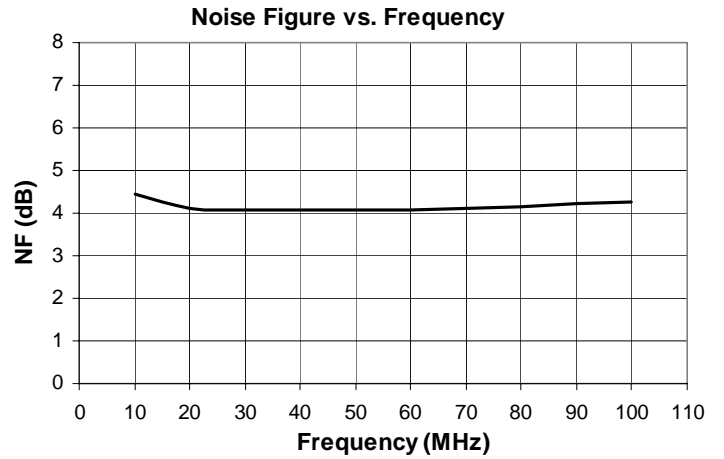
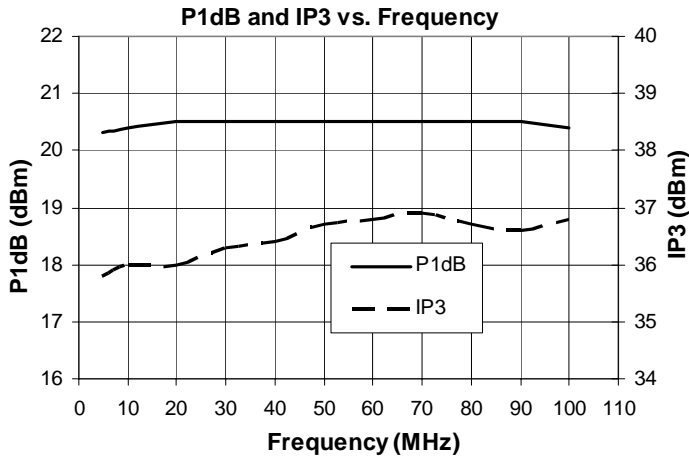
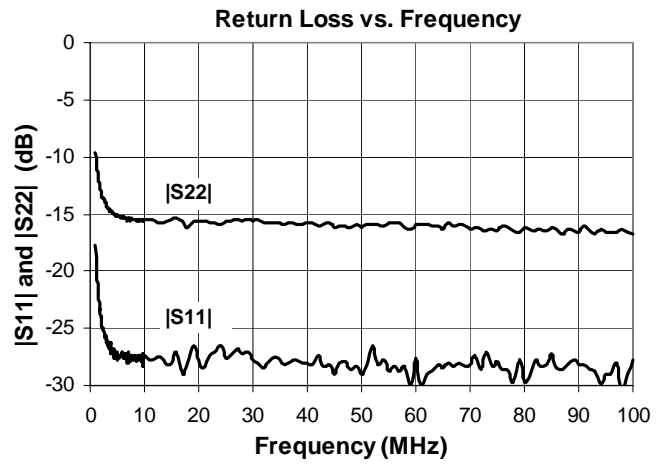
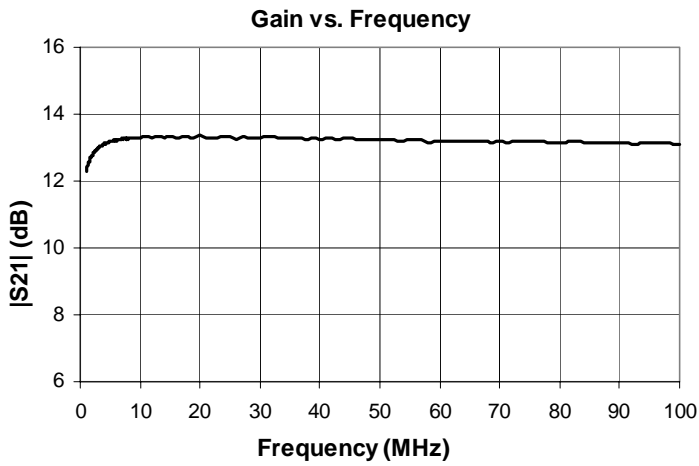
Recommended Bias Resistor Values for ID= 150mA				
Supply Voltage (V _s)	8V	9V	12V	15V
R _{BIAS}	51Ω	62Ω	100Ω	150Ω
R _{BIAS} Power Rating	1/2W	1/2W	1W	1W

$$R_{BIAS} = \frac{2(V_S - V_D)}{I_D}$$

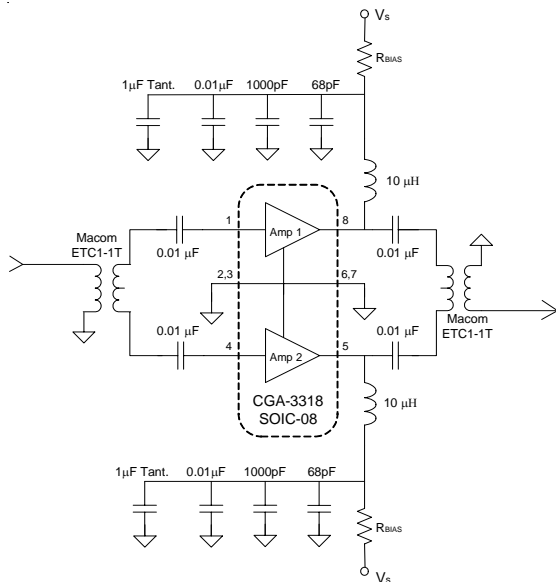
Part Number Ordering Information

Part Number	Reel Size	Devices / Reel
CGA-3318	7"	500
CGA-3318Z	7"	500

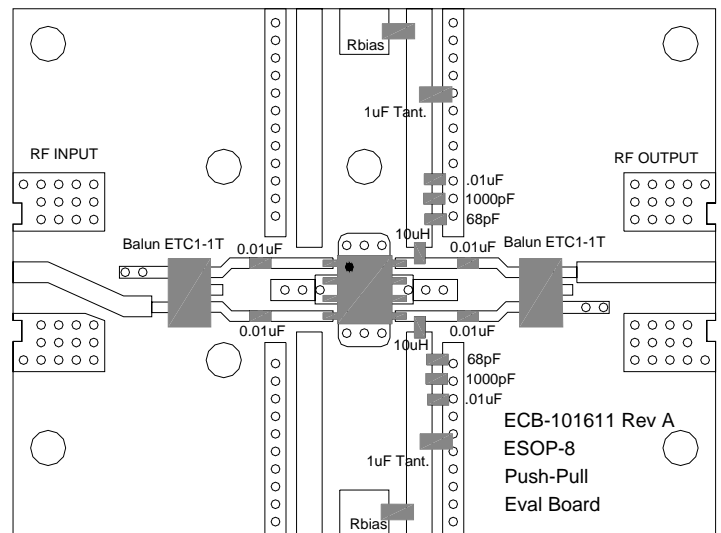
Typical 5-100 MHz RF Performance: $V_s=8V$, $I_D=150mA$ @ $T_L=+25^\circ C$, Push-Pull Configuration



5-100 MHz Application Schematic

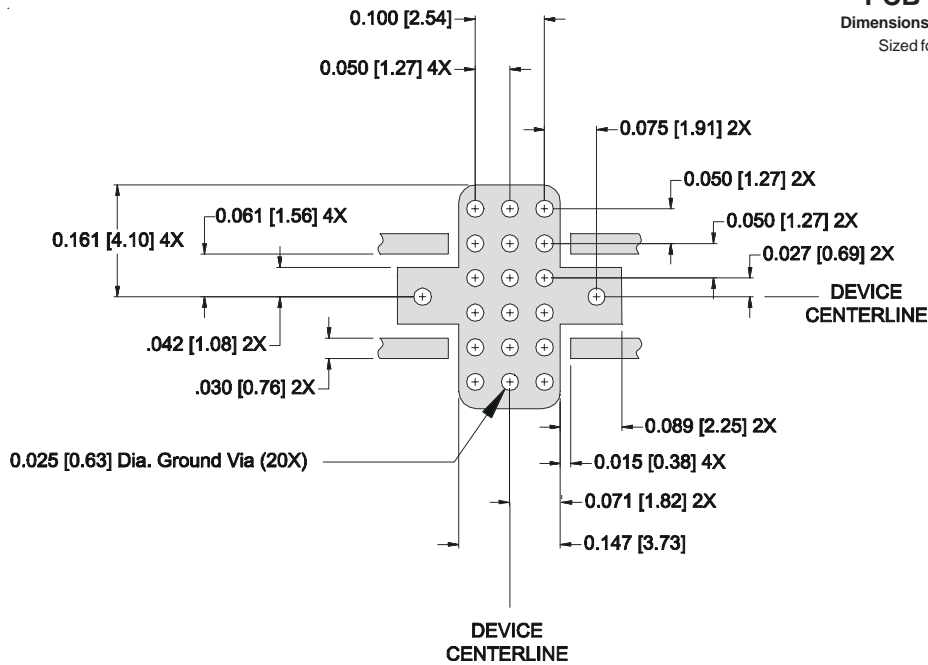


5-100 MHz Evaluation Board Layout



PCB Pad Layout

Dimensions in inches [millimeters]
Sized for 31 mil thick FR-4



Nominal Package Dimensions & Package Marking

Dimensions in inches [millimeters]

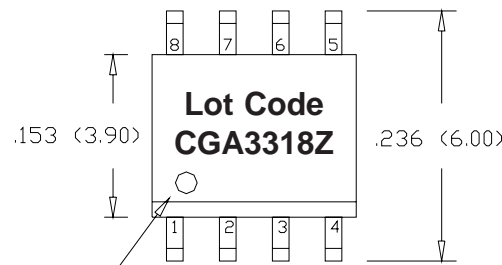
Refer to package drawing posted at www.sirenza.com for tolerances.

TOP VIEW

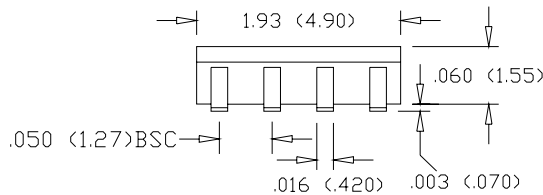
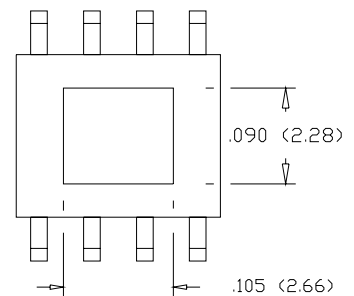
BOTTOM VIEW



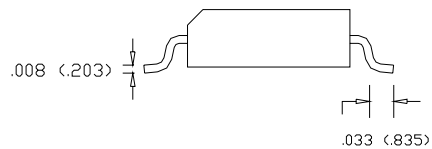
Tin-Lead



PIN 1 INDICATOR Lead Free



SIDE VIEW



END VIEW